2SC5788

Silicon NPN epitaxial planar type

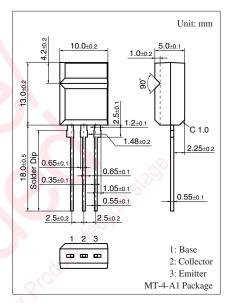
Power supply for Audio & Visual equipments such as TVs and VCRs Industrial equipments such as DC-DC converters

■ Features

- High-speed switching (t_{stg}: storage time/t_f: fall time is short)
- ullet Low collector to emitter saturation voltage $V_{CE(sat)}$
- Superior forward current transfer ratio h_{FE} linearity
- Allowing automatic insertion with radial taping

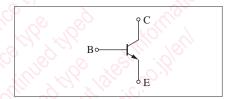
■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	60	V	
Collector-emitter voltage (Base open)	V_{CEO}	60	V	
Emitter-base voltage (Collector open)	V_{EBO}	6	V	
Collector current	I_{C}	3	A	
Peak collector current	I_{CP}	6	A	
Collector power $T_C = 25^{\circ}C$	P _C	15	W	
dissipation $T_a = 25^{\circ}C$		2	10,1	
Junction temperature	T_{j}	150	P°C	
Storage temperature	T_{stg}	-55 ~ +150	°C	



Marking Symbol: C5788

Internal Connection



■ Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

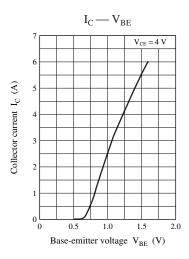
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 10 \text{ mA}, I_B = 0$	60			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 60 \text{ V}, I_E = 0$			100	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 60 \text{ V}, I_{B} = 0$			100	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 6 \text{ V}, I_C = 0$			1	mA
Forward current transfer ratio	h _{FE1} *	$V_{CE} = 4 \text{ V}, I_{C} = 1 \text{ A}$	120		320	_
	h _{FE2}	$V_{CE} = 4 \text{ V}, I_{C} = 3 \text{ A}$	40			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 3 \text{ A}, I_B = 375 \text{ mA}$			0.8	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.1 \text{ A}, f = 10 \text{ MHz}$		180		MHz
Turn-on time	t _{on}	$I_C = 1$ A, Resistance loaded		0.2	0.3	μs
Storage time	t _{stg}	$I_{B1} = 0.1 \text{ A}, I_{B2} = -0.1 \text{ A}$		0.55	0.7	μs
Fall time	$t_{\rm f}$	$V_{CC} = 50 \text{ V}$		0.1	0.15	μs

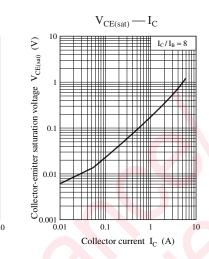
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

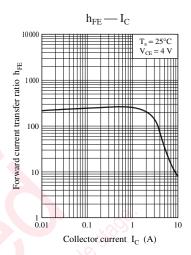
2. *: Rank classification

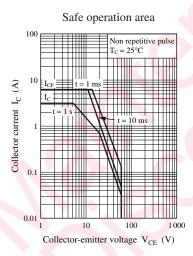
Rank	Р	Q
h_{FE1}	160 to 320	120 to 250

Panasonic









2 SJD00290AED

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